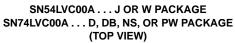
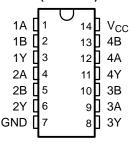
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FEATURES

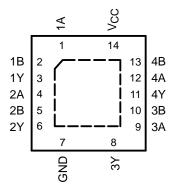
- Operate From 1.65 V to 3.6 V
- Specified From -40°C to 85°C, -40°C to 125°C, and -55°C to 125°C
- Inputs Accept Voltages to 5.5 V
- Max t_{pd} of 4.3 ns at 3.3 V
- Typical V_{OLP} (Output Ground Bounce)
 <0.8 V at V_{CC} = 3.3 V, T_A = 25°C
- Typical V_{OHV} (Output V_{OH} Undershoot)
 >2 V at V_{CC} = 3.3 V, T_A = 25°C

- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

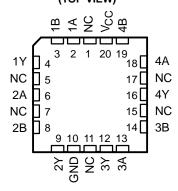




SN74LVC00A ... RGY PACKAGE (TOP VIEW)



SN54LVC00A . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

DESCRIPTION/ORDERING INFORMATION

The SN54LVC00A quadruple 2-input positive-NAND gate is designed for 2.7-V to 3.6-V V_{CC} operation, and the SN74LVC00A quadruple 2-input positive-NAND gate is designed for 1.65-V to 3.6-V V_{CC} operation.

The 'LVC00A devices perform the Boolean function $Y = \overline{A \bullet B}$ or $Y = \overline{A} + \overline{B}$ in positive logic.

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of these devices as translators in a mixed 3.3-V/5-V system environment.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

SN54LVC00A, SN74LVC00A QUADRUPLE 2-INPUT POSITIVE-NAND GATES

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ORDERING INFORMATION

T _A	PAC	(AGE ⁽¹⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 85°C	QFN – RGY	Reel of 1000	SN74LVC00ARGYR	LC00A
		Tube of 50	SN74LVC00AD	
	SOIC - D	Reel of 2500	SN74LVC00ADR	LVC00A
		Reel of 250	SN74LVC00ADT	
-40°C to 125°C	SOP - NS	Reel of 2000	SN74LVC00ANSR	LVC00A
-40 C to 125 C	SSOP - DB	Reel of 2000	SN74LVC00ADBR	LC00A
		Tube of 90	SN74LVC00APW	
	TSSOP - PW	Reel of 2000	SN74LVC00APWR	LC00A
		Reel of 250	SN74LVC00APWT	
	CDIP – J	Tube of 25	SNJ54LVC00AJ	SNJ54LVC00AJ
–55°C to 125°C	CFP – W	Tube of 150	SNJ54LVC00AW	SNJ54LVC00AW
	LCCC – FK	Tube of 55	SNJ54LVC00AFK	SNJ54LVC00AFK

⁽¹⁾ Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

FUNCTION TABLE (EACH GATE)

INP	OUTPUT	
Α	В	Y
Н	Н	L
L	Χ	Н
X	L	Н

LOGIC DIAGRAM, EACH GATE (POSITIVE LOGIC)







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Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	6.5	V
VI	Input voltage range (2)	Input voltage range ⁽²⁾		6.5	V
Vo	Output voltage range ⁽²⁾⁽³⁾		-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V _I < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current			±50	mA
V _{CC}	Continuous current through GND			±100	mA
		D package ⁽⁴⁾		86	
		DB package ⁽⁴⁾		96	
θ_{JA}	Package thermal impedance	NS package ⁽⁴⁾		76	°C/W
		PW package ⁽⁴⁾		113	
		RGY package ⁽⁵⁾		47	
T _{stg}	Storage temperature range	·	-65	150	°C
P _{tot}	Power dissipation ⁽⁶⁾⁽⁷⁾	$T_A = -40^{\circ}\text{C} \text{ to } 125^{\circ}\text{C}$		500	mW

Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

The value of V_{CC} is provided in the recommended operating conditions table.

The package thermal impedance is calculated in accordance with JESD 51-7.

The package thermal impedance is calculated in accordance with JESD 51-5.

For the D package: above 70°C, the value of P_{tot} derates linearly with 8 mW/K. For the DB, NS, and PW packages: above 60°C, the value of P_{tot} derates linearly with 5.5 mW/K.

SN54LVC00A, SN74LVC00A QUADRUPLE 2-INPUT POSITIVE-NAND GATES





Recommended Operating Conditions(1)

			SN54LV	SN54LVC00A -55°C to 125°C	
			−55°C to		
			MIN	MAX	
\/	Supply voltage	Operating	2	3.6	V
V_{CC}		Data retention only	1.5		V
V_{IH}	High-level input voltage	V _{CC} = 2.7 V to 3.6 V	2		V
V_{IL}	Low-level input voltage	V _{CC} = 2.7 V to 3.6 V		0.8	V
VI	Input voltage		0	5.5	V
Vo	Output voltage		0	V _{CC}	V
	High lavel autout august	V _{CC} = 2.7 V		-12	A
I _{OH}	High-level output current	V _{CC} = 3 V		-24	mA
	Low lovel output ourrent	V _{CC} = 2.7 V		12	A
I _{OL}	Low-level output current	V _{CC} = 3 V		24	- mA

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

Recommended Operating Conditions(1)

					SN74L	.VC00A				
			T _A =	$T_A = 25^{\circ}C$ $-40^{\circ}C$ to $85^{\circ}C$ $-40^{\circ}C$ to $125^{\circ}C$		$T_A = 25^{\circ}C$ $-40^{\circ}C$ to $85^{\circ}C$ $-40^{\circ}C$ to $125^{\circ}C$		o 125°C	UNIT	
			MIN	MAX	MIN	MAX	MIN	MAX		
\/	Supply voltage	Operating	1.65	3.6	1.65	3.6	1.65	3.6	V	
V _{CC}		Data retention only	1.5		1.5		1.5		V	
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	$0.65 \times V_{CC}$		$0.65 \times V_{CC}$		$0.65 \times V_{CC}$			
V_{IH}	High-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7		1.7		1.7		V	
	input voltage	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2		2		2			
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		$0.35 \times V_{CC}$		$0.35 \times V_{CC}$		$0.35 \times V_{CC}$		
V_{IL}	Low-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7		0.7		0.7	V	
	input voltage	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		0.8		0.8		0.8		
VI	Input voltage	·	0	5.5	0	5.5	0	5.5	V	
V_{O}	Output voltage		0	V_{CC}	0	V _{CC}	0	V_{CC}	V	
		V _{CC} = 1.65 V		-4		-4		-4		
	High-level	V _{CC} = 2.3 V		-8		-8		-8	A	
I _{OH}	output current	V _{CC} = 2.7 V		-12		-12		-12	mA	
		$V_{CC} = 3 V$		-24		-24		-24		
		V _{CC} = 1.65 V		4		4		4		
	Low-level	V _{CC} = 2.3 V		8		8		8	A	
l _{OL}	output current	$V_{CC} = 2.7 \text{ V}$		12		12		12	mA	
		$V_{CC} = 3 V$		24		24		24		

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

			SN54LVC00A	
PARAMETER	TEST CONDITIONS	V _{cc}	–55°C to 125°C	UNIT
			MIN MAX	
	$I_{OH} = -100 \mu A$	2.7 V to 3.6 V	V _{CC} - 0.2	
\/	L - 12 mA	2.7 V	2.2	V
V _{OH}	$I_{OH} = -12 \text{ mA}$	3 V	2.4	V
	$I_{OH} = -24 \text{ mA}$	3 V	2.2	
	I _{OL} = 100 μA	2.7 V to 3.6 V	0.2	
V_{OL}	I _{OL} = 12 mA	2.7 V	0.4	V
	I _{OL} = 24 mA	3 V	0.55	
I _I	$V_I = 5.5 \text{ V or GND}$	3.6 V	±5	μΑ
I _{CC}	$V_I = V_{CC}$ or GND, $I_O = 0$	3.6 V	10	μΑ
ΔI_{CC}	One input at V_{CC} – 0.6 V, Other inputs at V_{CC} or GND	2.7 V to 3.6 V	500	μΑ

Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

					S	N74LVC00A	\				
PARAMETER	TEST CONDITIONS	V _{cc}	T _A = 25°C		-40°C to 85°C		–40°C to 125°C		UNIT		
			MIN	TYP	MAX	MIN	MAX	MIN	MAX		
	$I_{OH} = -100 \mu A$	1.65 V to 3.6 V	V _{CC} - 0.2			V _{CC} - 0.2		$V_{CC} - 0.3$			
	$I_{OH} = -4 \text{ mA}$	1.65 V	1.29			1.2		1.05			
V	$I_{OH} = -8 \text{ mA}$	2.3 V	1.9			1.7		1.55		V	
V _{OH}	I _{OH} = -12 mA	2.7 V	2.2			2.2		2.05		V	
	10H = -12 IIIA	3 V	2.4			2.4		2.25			
	$I_{OH} = -24 \text{ mA}$	3 V	2.3			2.2		2			
	I _{OL} = 100 μA	1.65 V to 3.6 V			0.1		0.2		0.3		
	I _{OL} = 4 mA	1.65 V			0.24		0.45		0.6	V	
V _{OL}	$I_{OL} = 8 \text{ mA}$	2.3 V			0.3		0.7		0.85		
	I _{OL} = 12 mA	2.7 V			0.4		0.4		0.6		
	I _{OL} = 24 mA	3 V			0.55		0.55		0.8		
I _I	$V_I = 5.5 \text{ V or GND}$	3.6 V			±1		±5		±20	μΑ	
Icc	$V_I = V_{CC}$ or GND, $I_O = 0$	3.6 V			1		10		40	μΑ	
Δl _{CC}	One input at V _{CC} – 0.6 V, Other inputs at V _{CC} or GND	2.7 V to 3.6 V			500		500		5000	μΑ	
C _i	V _I = V _{CC} or GND	3.3 V		5						pF	

SN54LVC00A, SN74LVC00A QUADRUPLE 2-INPUT POSITIVE-NAND GATES





Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

	PARAMETER				SN54LV	UNIT	
		FROM (INPUT)	TO (OUTPUT)	V _{cc}	–55°C to 125°C		
			(331.31)		MIN	MAX	
		A or B	V	2.7 V		5.1	20
	r _{pd} A of B	AUB	I	3.3 V \pm 0.3 V	1	4.3	ns

Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

							SN74L\	/C00A			
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{cc}	T,	T _A = 25°C		-40°C to 85°C		–40°C to 125°C		UNIT
(IIII O1)	(6611 61)		MIN	TYP	MAX	MIN	MAX	MIN	MAX		
			1.8 V ± 0.15 V	1	6	12	1	12.5	1	14	
	A = = B	V	2.5 V ± 0.2 V	1	4.6	5.9	1	6.4	1	7.9	
t _{pd}	AUIB	A or B Y	2.7 V	1	4.3	4.9	1	5.1	1	6.5	ns
		3.3 V ± 0.3 V	1	3.5	4.1	1	4.3	1	5.5		
t _{sk(o)}			$3.3~\text{V}\pm0.3~\text{V}$					1		1.5	ns

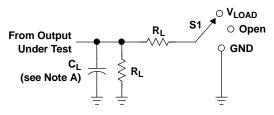
Operating Characteristics

 $T_A = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	V _{CC}	TYP	UNIT
			1.8 V	18	
C_{pd}	Power dissipation capacitance per gate	f = 10 MHz	2.5 V	18	pF
			3.3 V	19	



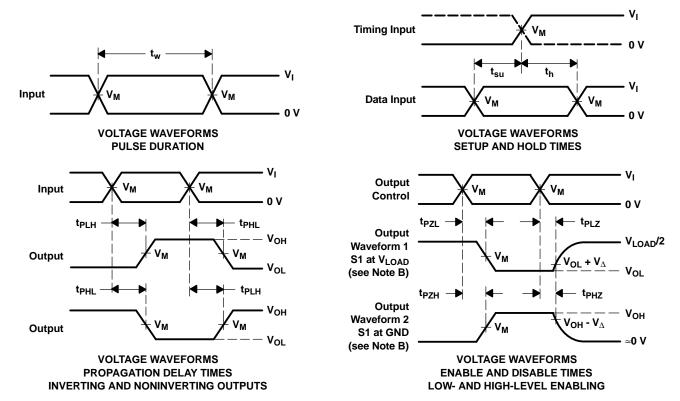
PARAMETER MEASUREMENT INFORMATION



TEST	S1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	V _{LOAD}
t _{PHZ} /t _{PZH}	GND

LOAD CIRCUIT

.,	INPUTS		.,	.,		_	.,	
V _{CC}	V _I	t _r /t _f	V _M	V _{LOAD}	CL	R _L	V_Δ	
1.8 V \pm 0.15 V	v _{cc}	≤ 2 ns	V _{CC} /2	2×V _{CC}	30 pF	1 k Ω	0.15 V	
2.5 V \pm 0.2 V	V _{CC}	≤ 2 ns	V _{CC} /2	2×V _{CC}	30 pF	500 Ω	0.15 V	
2.7 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V	
3.3 V \pm 0.3 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V	



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_0 = 50 \ \Omega$.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en}.
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .
- H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms

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PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
5962-9753301Q2A	ACTIVE	LCCC	FK	20	1	TBD	Call TI	Call TI	
5962-9753301QCA	ACTIVE	CDIP	J	14	1	TBD	Call TI	Call TI	
5962-9753301QDA	ACTIVE	CFP	W	14	1	TBD	Call TI	Call TI	
5962-9753301V2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	
5962-9753301VCA	ACTIVE	CDIP	J	14	25	TBD	A42	N / A for Pkg Type	
5962-9753301VDA	ACTIVE	CFP	W	14	1	TBD	A42	N / A for Pkg Type	
SN74LVC00AD	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC00ADBLE	OBSOLETE	SSOP	DB	14		TBD	Call TI	Call TI	
SN74LVC00ADBR	ACTIVE	SSOP	DB	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC00ADBRE4	ACTIVE	SSOP	DB	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC00ADBRG4	ACTIVE	SSOP	DB	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC00ADE4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC00ADG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC00ADR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC00ADRE4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC00ADRG4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC00ADT	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC00ADTE4	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC00ADTG4	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC00ANSR	ACTIVE	SO	NS	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	





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Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
SN74LVC00ANSRG4	ACTIVE	SO	NS	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC00APW	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC00APWE4	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC00APWG4	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC00APWLE	OBSOLETE	TSSOP	PW	14		TBD	Call TI	Call TI	
SN74LVC00APWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC00APWRE4	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC00APWRG3	PREVIEW	TSSOP	PW	14	2000	TBD	Call TI	Call TI	
SN74LVC00APWRG4	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC00APWT	ACTIVE	TSSOP	PW	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC00APWTE4	ACTIVE	TSSOP	PW	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC00APWTG4	ACTIVE	TSSOP	PW	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVC00ARGYR	ACTIVE	VQFN	RGY	14	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
SN74LVC00ARGYRG4	ACTIVE	VQFN	RGY	14	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
SNJ54LVC00AFK	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	
SNJ54LVC00AJ	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	
SNJ54LVC00AW	ACTIVE	CFP	W	14	1	TBD	A42	N / A for Pkg Type	

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

PACKAGE OPTION ADDENDUM



28-Aug-2012

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN54LVC00A, SN54LVC00A-SP, SN74LVC00A:

Catalog: SN74LVC00A, SN54LVC00A

Automotive: SN74LVC00A-Q1, SN74LVC00A-Q1

Enhanced Product: SN74LVC00A-EP, SN74LVC00A-EP

Military: SN54LVC00A

Space: SN54LVC00A-SP

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product Supports Defense, Aerospace and Medical Applications



28-Aug-2012

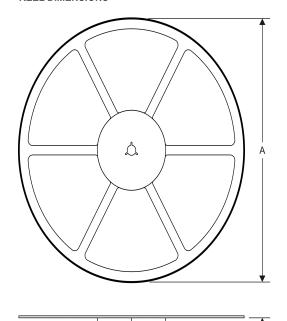
- Military QML certified for Military and Defense Applications
- Space Radiation tolerant, ceramic packaging and qualified for use in Space-based application

PACKAGE MATERIALS INFORMATION

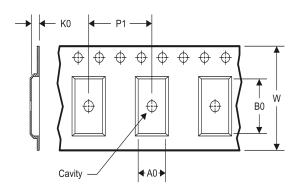
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TAPE AND REEL INFORMATION

REEL DIMENSIONS



TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

All dimensions are nominal	1	1				1		1				
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC00ADBR	SSOP	DB	14	2000	330.0	16.4	8.2	6.6	2.5	12.0	16.0	Q1
SN74LVC00ADR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74LVC00ADR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74LVC00ADT	SOIC	D	14	250	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74LVC00ANSR	SO	NS	14	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
SN74LVC00APWR	TSSOP	PW	14	2000	330.0	12.4	7.0	5.6	1.6	8.0	12.0	Q1
SN74LVC00APWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC00APWRG4	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC00APWT	TSSOP	PW	14	250	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC00ARGYR	VQFN	RGY	14	3000	330.0	12.4	3.75	3.75	1.15	8.0	12.0	Q1

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*All dimensions are nominal

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
SN74LVC00ADBR	SSOP	DB	14	2000	367.0	367.0	38.0	
SN74LVC00ADR	SOIC	D	14	2500	333.2	345.9	28.6	
SN74LVC00ADR	SOIC	D	14	2500	367.0	367.0	38.0	
SN74LVC00ADT	SOIC	D	14	250	367.0	367.0	38.0	
SN74LVC00ANSR	SO	NS	14	2000	367.0	367.0	38.0	
SN74LVC00APWR	TSSOP	PW	14	2000	364.0	364.0	27.0	
SN74LVC00APWR	TSSOP	PW	14	2000	367.0	367.0	35.0	
SN74LVC00APWRG4	TSSOP	PW	14	2000	367.0	367.0	35.0	
SN74LVC00APWT	TSSOP	PW	14	250	367.0	367.0	35.0	
SN74LVC00ARGYR	VQFN	RGY	14	3000	367.0	367.0	35.0	

14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

W (R-GDFP-F14)

CERAMIC DUAL FLATPACK



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only.
- E. Falls within MIL STD 1835 GDFP1-F14 and JEDEC MO-092AB



FK (S-CQCC-N**)

LEADLESS CERAMIC CHIP CARRIER

28 TERMINAL SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a metal lid.
- D. Falls within JEDEC MS-004



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
 - Sody length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) package configuration.
- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
- G. Package complies to JEDEC MO-241 variation BA.



RGY (S-PVQFN-N14)

PLASTIC QUAD FLATPACK NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

Exposed Thermal Pad Dimensions

4206353-2/0 11/11

NOTE: All linear dimensions are in millimeters



RGY (S-PVQFN-N14)

PLASTIC QUAD FLATPACK NO-LEAD



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat—Pack QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com http://www.ti.com.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150

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